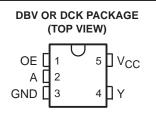
SN74LVC1G126 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

SCES224K - APRIL 1999 - REVISED SEPTEMBER 2003

- Available in the Texas Instruments NanoStar[™] and NanoFree[™] Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 3.7 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

description/ordering information



YEA, YEP, YZA, OR YZP PACKAGE (BOTTOM VIEW)

GND	03	40	Y
Α	02		Vcc
OE	01	50	V _{CC}

This single bus buffer gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G126 is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is low.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

TA	PACKAGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING [‡]	
	NanoStar™ – WCSP (DSBGA) 0.17-mm Small Bump – YEA		SN74LVC1G126YEAR	
	NanoFree™ – WCSP (DSBGA) 0.17-mm Small Bump – YZA (Pb-free)	Deal of 2000	SN74LVC1G126YZAR	CN
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Reel of 3000	SN74LVC1G126YEPR	CN_
−40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)		SN74LVC1G126YZPR	
		Reel of 3000	SN74LVC1G126DBVR	0.00
	SOT (SOT-23) – DBV	Reel of 250	SN74LVC1G126DBVT	C26_
		Reel of 3000	SN74LVC1G126DCKR	CN
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G126DCKT	CN_

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YEA/YZA, YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code,

and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition $(1 = SnPb, \bullet = Pb-free).$



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar and NanoFree are trademarks of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



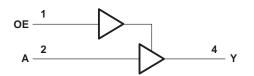
description/ordering information (continued)

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

FUNCTION TABLE							
INPU	JTS	OUTPUT					
OE	Α	Y					
н	Н	Н					
н	L	L					
L	Х	Z					

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, V _O	
(see Note 1)	–0.5 v 10 6.5 v
(see Notes 1 and 2)	–0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I_{OK} (V _O < 0)	
Continuous output current, I _O	
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DBV package	
DCK package	
YEA/YZA package	
YEP/YZP package	132°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The value of V_{CC} is provided in the recommended operating conditions table.

3. The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
\/	Cumphuseltere	Operating	1.65	5.5	V	
Vcc	Supply voltage	Data retention only	1.5		v	
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
	Lich lovel input veltere	V_{CC} = 2.3 V to 2.7 V	1.7		V	
VIH	VIH High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V	
		V_{CC} = 4.5 V to 5.5 V	$0.7 \times V_{CC}$			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
Ma		V_{CC} = 2.3 V to 2.7 V		0.7	V	
VIL	Low-level input voltage	$V_{CC} = 3 \vee to 3.6 \vee$		0.8	V	
	V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$			
VI	Input voltage		0	5.5	V	
VO	Output voltage		0	VCC	V	
		V _{CC} = 1.65 V		-4		
		$V_{CC} = 2.3 V$		-8	1	
ЮН	High-level output current	V _{CC} = 3 V		-16	mA	
		VCC = 3 V		-24		
		$V_{CC} = 4.5 V$		-32		
		V _{CC} = 1.65 V		4		
		$V_{CC} = 2.3 V$		8		
IOL	Low-level output current	$V_{CC} = 3 V$		16	mA	
		000 = 3 0		24		
		$V_{CC} = 4.5 V$		32		
		V_{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V		20		
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 3.3 V ± 0.3 V		10	ns/V	
		$V_{CC} = 5 V \pm 0.5 V$		5		
Тд	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN74LVC1G126 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

SCES224K - APRIL 1999 - REVISED SEPTEMBER 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP† I	MAX	UNIT
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} -0.1			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			V
Voh	$I_{OH} = -16 \text{ mA}$	2.1/	2.4			V
	$I_{OH} = -24 \text{ mA}$	3 V	2.3			
	I _{OH} = -32 mA	4.5 V	3.8			
	I _{OL} = 100 μA	1.65 V to 5.5 V			0.1	
	I _{OL} = 4 mA	1.65 V			0.45	
	I _{OL} = 8 mA	2.3 V			0.3	
VOL	I _{OL} = 16 mA	2.1/			0.4	V
	I _{OL} = 24 mA	3 V			0.55	
	I _{OL} = 32 mA	4.5 V			0.55	
II A or OE inputs	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V			±5	μΑ
l _{off}	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	0			±10	μΑ
I _{OZ}	$V_{O} = 0$ to 5.5 V	3.6 V			10	μA
ICC	$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V			10	μΑ
ΔICC	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 5.5 V			500	μΑ
Ci	$V_{I} = V_{CC}$ or GND	3.3 V		4		pF

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25° C.

switching characteristics over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.		V _{CC} = ± 0.		V _{CC} : ± 0.		UNIT
		(001101)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t pd	A	Y	1.7	6.9	0.6	4.6	0.6	3.7	0.5	3.4	ns

switching characteristics over recommended operating free-air temperature range, CL = 30 pF or 50 pF (unless otherwise noted) (see Figure 2)

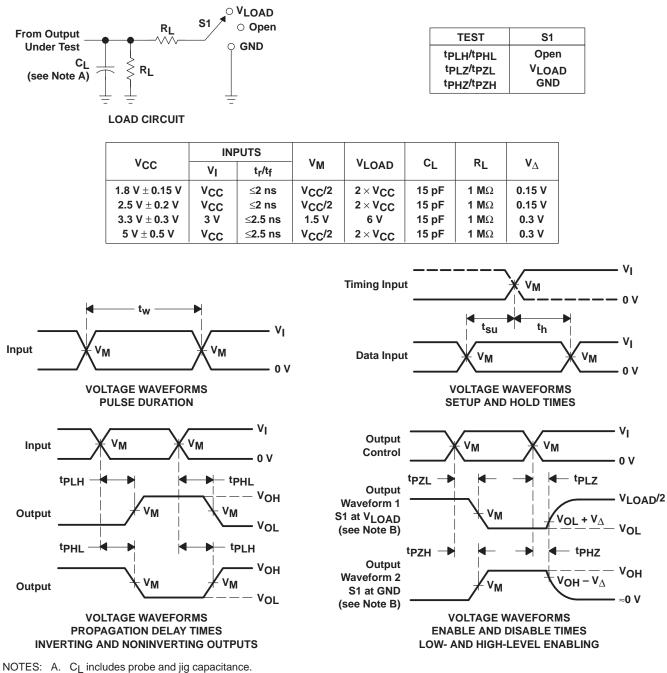
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.		V _{CC} = ± 0.		۲ <mark>۰۵</mark> کا ۲۰۰۰ کا		UNIT
		(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
^t pd	A	Y	2.6	8	1.1	5.5	1	4.5	1	4	ns
t _{en}	OE	Y	2.8	9.4	1.3	6.6	1.2	5.3	1	5	ns
^t dis	OE	Y	1.6	9.8	1	5.5	1	5.5	1	4.2	ns

operating characteristics, $T_A = 25^{\circ}C$

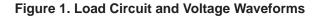
	PARAMETER		TEST	V _{CC} = 1.8 V	$V_{CC} = 2.5 V$	V _{CC} = 3.3 V	V _{CC} = 5 V	UNIT
	FARAINETER	CONDITIONS	TYP	TYP	TYP	TYP	UNIT	
Card	Power dissipation	Outputs enabled	f = 10 MHz	19	19	19	21	рF
Cpd	capacitance	Outputs disabled		2	2	3	4	рг



PARAMETER MEASUREMENT INFORMATION

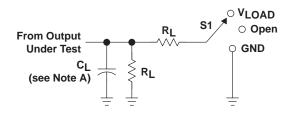


- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω .
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.





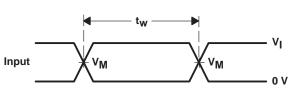
PARAMETER MEASUREMENT INFORMATION

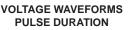


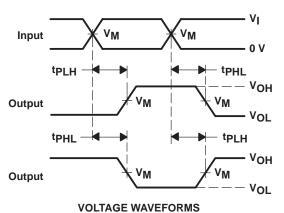
LOAD CIRCUIT

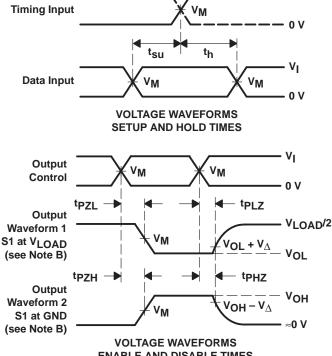
TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
^t PHZ ^{/t} PZH	GND

	INF	PUTS			•	_	
VCC	VI	t _r /t _f	VM	VLOAD	CL	RL	v_Δ
1.8 V \pm 0.15 V	Vcc	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	Vcc	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V









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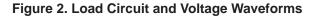
ENABLE AND DISABLE TIMES

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 $\Omega.$
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.

PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.



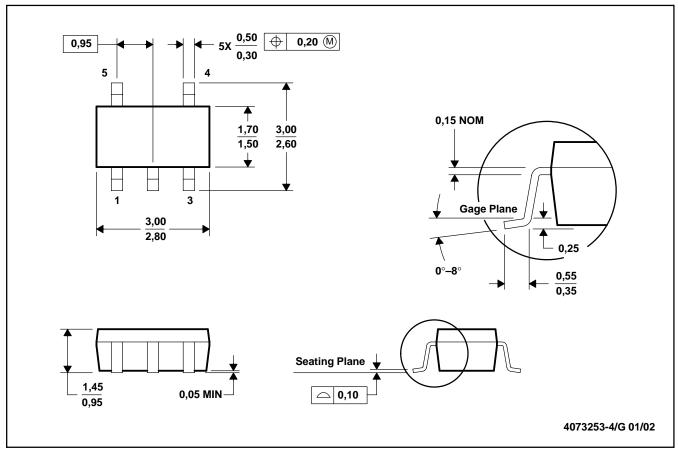


MECHANICAL DATA

MPDS018E - FEBRUARY 1996 - REVISED FEBRUARY 2002

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

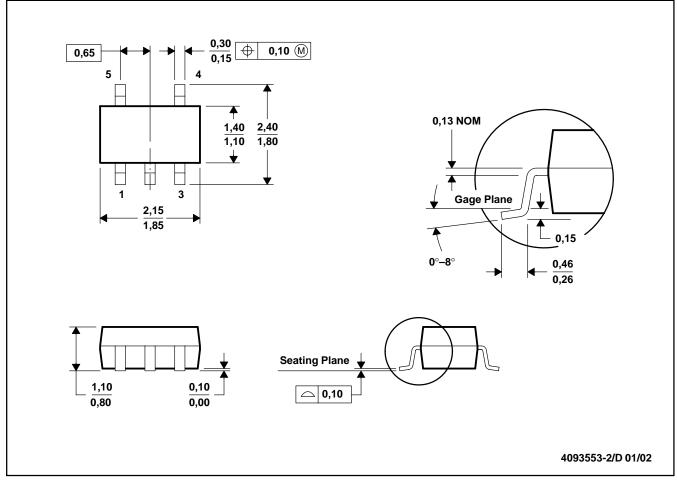
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178



MPDS025C - FEBRUARY 1997 - REVISED FEBRUARY 2002

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



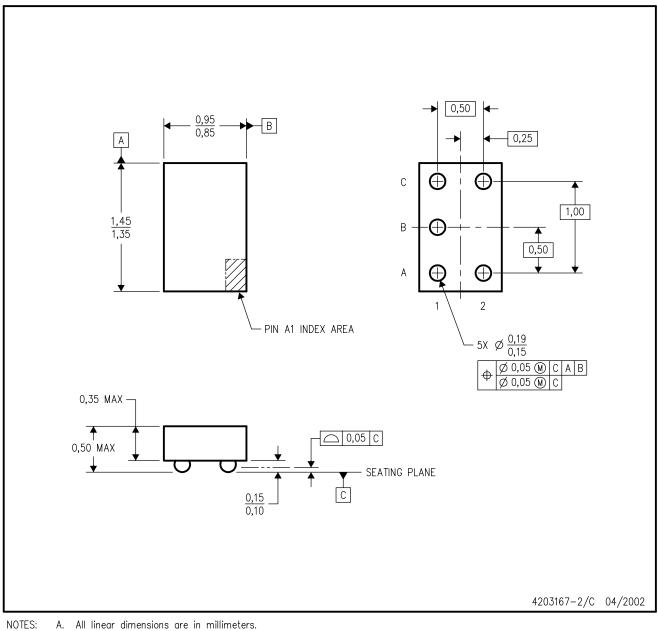
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203



YEA (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



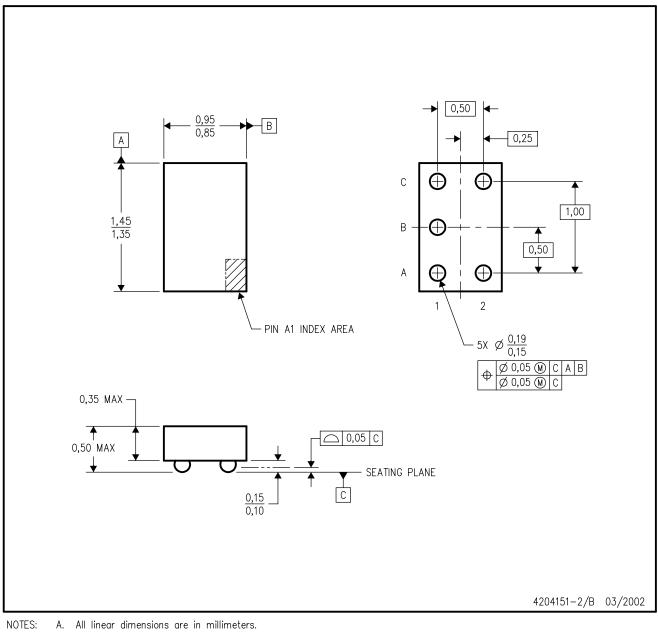
- B. This drawing is subject to change without notice.
- C. NanoStar™ package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is tin-lead (SnPb). Refer to the 5 YZA package (drawing 4204151) for lead-free.

NanoStar is a trademark of Texas Instruments.



YZA (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



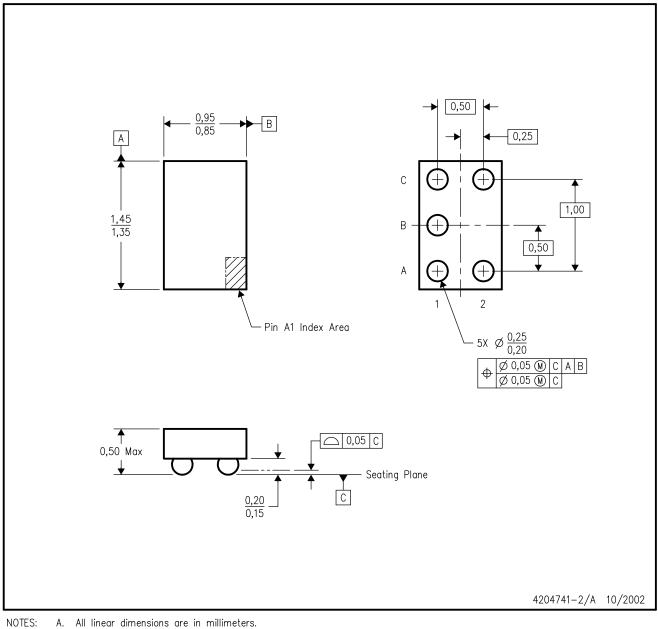
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is lead-free. Refer to the 5 YEA package (drawing 4203167) for tin-lead (SnPb).

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YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



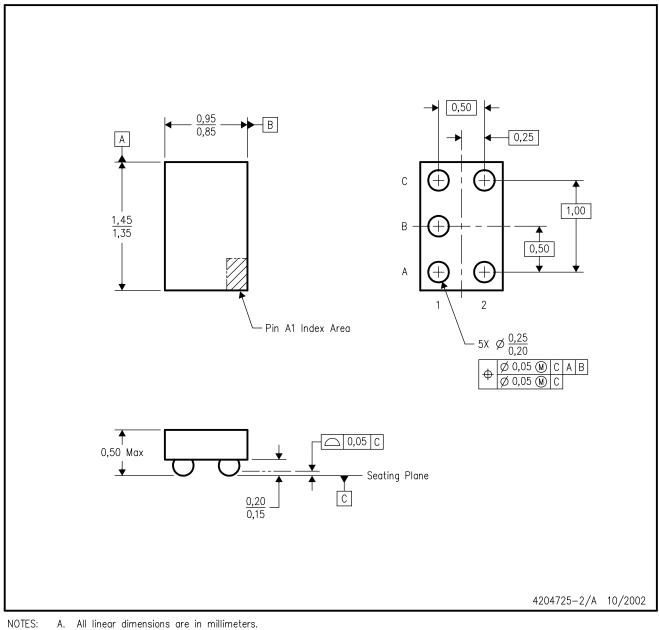
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

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YEP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

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